

ON Semiconductor

Is Now

The logo for onsemi, featuring the word "onsemi" in a dark teal, lowercase, sans-serif font. The letter "i" is stylized with a white dot and a teal vertical bar. A small orange triangle is positioned above the top right of the "i". A trademark symbol (TM) is located to the right of the logo.

To learn more about onsemi™, please visit our website at
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QED234

Plastic Infrared Light Emitting Diode

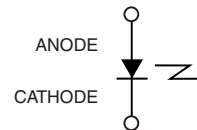
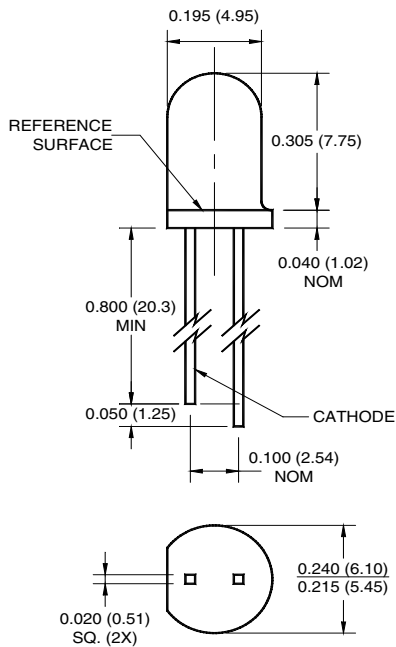
Features

- $\lambda = 940$ nm
- Chip Material = GaAs with AlGaAs Window
- Package Type: T-1 3/4 (5 mm lens diameter)
- Matched Photosensor: QSD123/124
- Medium Emission Angle, 40°
- High Output Power
- Package Material and Color: Clear, Untinted, Plastic
- Ideal for Remote Control Applications

Description

The QED234 is a 940 nm GaAs / AlGaAs LED encapsulated in a clear untinted, plastic T-1 3/4 package.

Package Dimensions^(1, 2)



Notes:

1. Dimensions for all drawings are in inches (mm).
2. Tolerance of ± 0.010 (0.25) on all non-nominal dimensions unless otherwise specified.

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Value	Unit
T_{OPR}	Operating Temperature	-40 to +100	$^\circ\text{C}$
T_{STG}	Storage Temperature	-40 to +100	$^\circ\text{C}$
T_{SOL-I}	Soldering Temperature (Iron) ^(4, 5, 6)	240 for 5 sec	$^\circ\text{C}$
T_{SOL-F}	Soldering Temperature (Flow) ^(4, 5)	260 for 10 sec	$^\circ\text{C}$
I_F	Continuous Forward Current	100	mA
V_R	Reverse Voltage	5	V
P_D	Power Dissipation ⁽³⁾	200	mW
I_{FP}	Peak Forward Current	1.5	A

Notes:

3. Derate power dissipation linearly 2.67 mW/ $^\circ\text{C}$ above 25 $^\circ\text{C}$.
4. RMA flux is recommended.
5. Methanol or isopropyl alcohols are recommended as cleaning agents.
6. Soldering iron 1/16" (1.6mm) minimum from housing.
7. Pulse conditions; $t_p = 100 \mu\text{s}$, $T = 10 \text{ ms}$

Electrical / Optical Characteristics

Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
λ_{PE}	Peak Emission Wavelength	$I_F = 20 \text{ mA}$		940		nm
-	Spectral Bandwidth	$I_F = 20 \text{ mA}$	50			nm
TC_λ	Temp. Coefficient of λ_{PE}	$I_F = 100 \text{ mA}$		0.2		nm/K
$2\theta_{1/2}$	Emission Angle	$I_F = 100 \text{ mA}$		40		$^\circ$
V_F	Forward Voltage	$I_F = 100 \text{ mA}$, $t_p = 20 \text{ ms}$			1.6	V
TC_V	Temp. Coefficient of V_F	$I_F = 100 \text{ mA}$		-1.5		mV/K
I_R	Reverse Current	$V_R = 5 \text{ V}$			10	μA
I_E	Radiant Intensity	$I_F = 100 \text{ mA}$, $t_p = 20 \text{ ms}$	27			mW/sr
TC_I	Temp. Coefficient of IE	$I_F = 20 \text{ mA}$		-0.6		%/K
t_r	Rise Time	$I_F = 100 \text{ mA}$		1000		ns
t_f	Fall Time			1000		ns

Typical Performance Characteristics

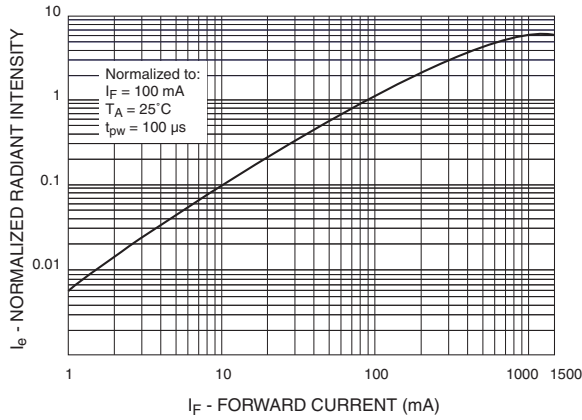


Figure 1. Normalized Radiant Intensity vs. Forward Current

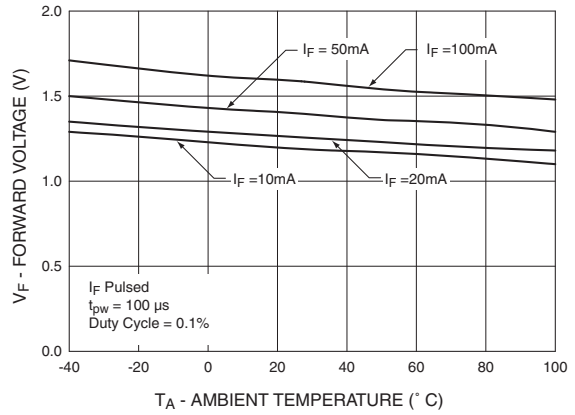


Figure 2. Forward Voltage vs. Ambient Temperature

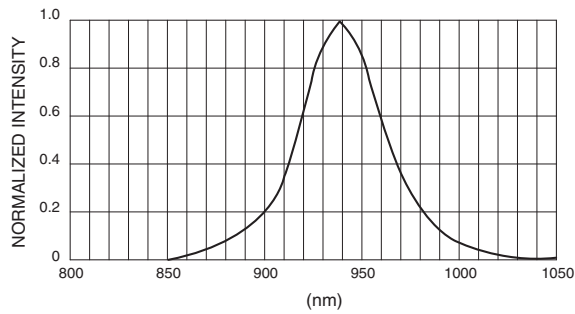


Figure 3. Normalized Radiant Intensity vs. Wavelength

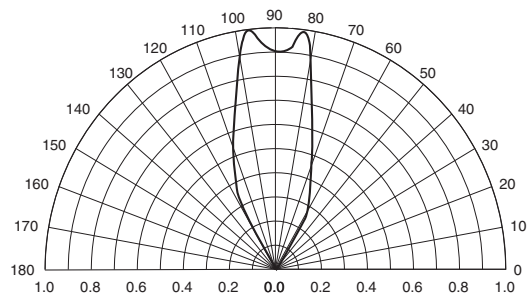


Figure 4. Radiant Diagram

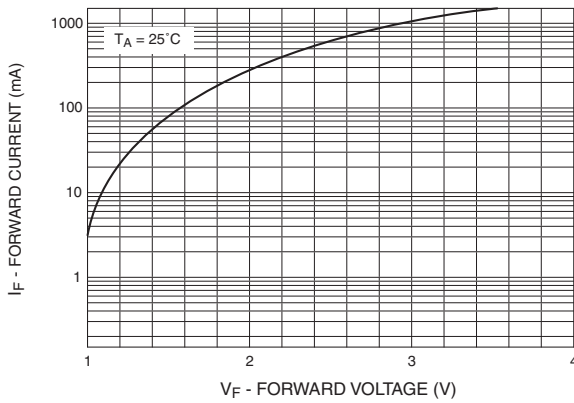


Figure 5. Forward Current vs. Forward Voltage

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